



**OPTICALLY COUPLED BILATERAL
 SWITCH LIGHT ACTIVATED ZERO
 VOLTAGE CROSSING TRIAC**

'X' SPECIFICATION APPROVALS

- VDE 0884 in 3 available lead form : -
 - STD
 - G form
 - SMD approved to CECC 00802

DESCRIPTION

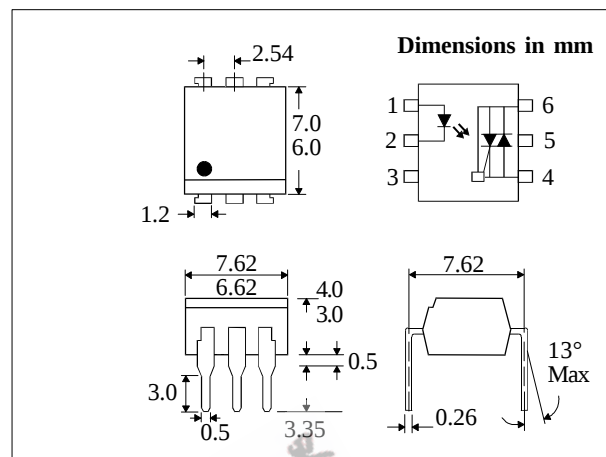
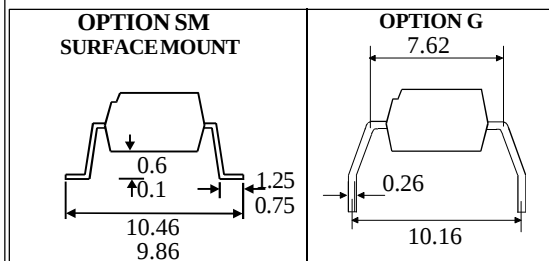
The MOC304_ Series are optically coupled isolators consisting of a Gallium Arsenide infrared emitting diode coupled with a monolithic silicon detector performing the functions of a zero crossing bilateral triac mounted in a standard 6 pin dual-in-line package.

FEATURES

- Options :-
 10mm lead spread - add G after part no.
 Surface mount - add SM after part no.
 Tape&reel - add SMT&R after part no.
- High Isolation Voltage (5.3kV_{RMS}, 7.5kV_{PK})
- Zero Voltage Crossing
- 400V Peak Blocking Voltage
- All electrical parameters 100% tested
- Custom electrical selections available

APPLICATIONS

- CRTs
- Power Triac Driver
- Motors
- Consumer appliances
- Printers



ABSOLUTE MAXIMUM RATINGS
 (25 °C unless otherwise noted)

Storage Temperature	-55°C - +150°C
Operating Temperature	-40°C - +100°C
Lead Soldering Temperature	260°C
(1.6mm from case for 10 seconds)	

INPUT DIODE

Forward Current	50mA
Reverse Voltage	6V
Power Dissipation	120mW
(derate linearly 1.41mW/°C above 25°C)	

OUTPUT PHOTO TRIAC

Off-State Output Terminal Voltage	400V
Forward Current (Peak)	1A
Power Dissipation	150mW
(derate linearly 1.76mW/°C above 25°C)	

POWER DISSIPATION

Total Power Dissipation	250mW
(derate linearly 2.94mW/°C above 25°C)	

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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)		1.2	1.4	V	$I_F = 20\text{mA}$
	Reverse Current (I_R)			10	μA	$V_R = 6\text{V}$
Output	Peak Off-state Current (I_{DRM})	400		500	nA	$V_{\text{DRM}} = 400\text{V}$ (note 1)
	Peak Blocking Voltage (V_{DRM})				V	$I_{\text{DRM}} = 500\text{nA}$
	On-state Voltage (V_{TM})			3.0	V	$I_{\text{TM}} = 100\text{mA}$ (peak)
	Critical rate of rise of off-state Voltage (dv/dt)	600	1500		V/ μs	
Coupled	Input Current to Trigger (I_{FT}) (note 2) MOC3040 MOC3041 MOC3042 MOC3043			30 15 10 5	mA mA mA mA	$V_{\text{TM}} = 3\text{V}$ (note 2)
	Holding Current , either direction (I_H) Input to Output Isolation Voltage V_{ISO}	5300 7500	400		μA V_{RMS} V_{PK}	See note 3 See note 3
Zero Crossing Characteristic	Inhibit Voltage (V_{IH})			20	V	$I_F = \text{Rated } I_{\text{FT}}$ MT1-MT2 Voltage above which device will not trigger
	Leakage in Inhibited State (I_S)			500	mA	$I_F = \text{Rated } I_{\text{FT}}$ $V_{\text{DRM}} = \text{Rated } V_{\text{DRM}}$ Off-state

Note 1. Test voltage must be applied within dv/dt rating.

Note 2. Guaranteed to trigger at an I_F value less than or equal to max. I_{FT} , recommended I_F lies between Rated I_{FT} and absolute max. I_F .

Note 3. Measured with input leads shorted together and output leads shorted together.

CHARACTERISTIC CURVES

Fig.1 Forward Current vs. Ambient Temperature

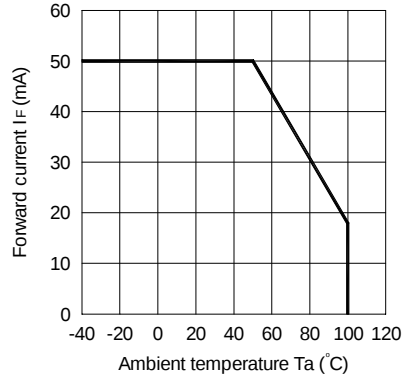


Fig.2 On-state Current vs. Ambient Temperature

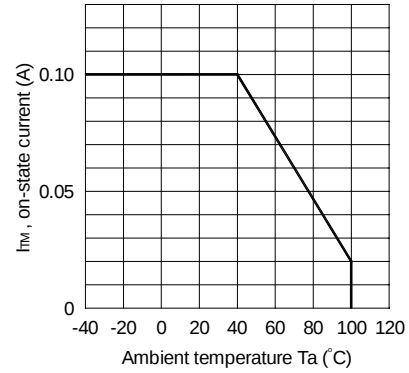


Fig.3 Minimum Trigger Current vs. Ambient Temperature

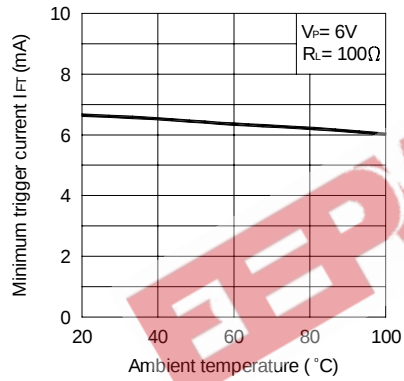


Fig.4 Forward Current vs. Forward Voltage

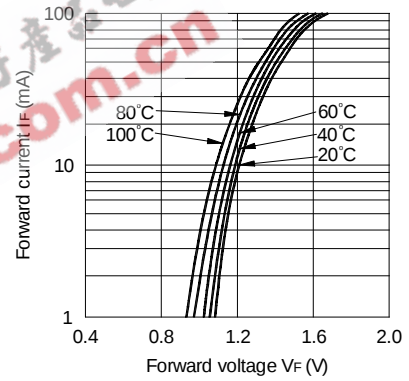


Fig.5 On-state Voltage vs. Ambient Temperature

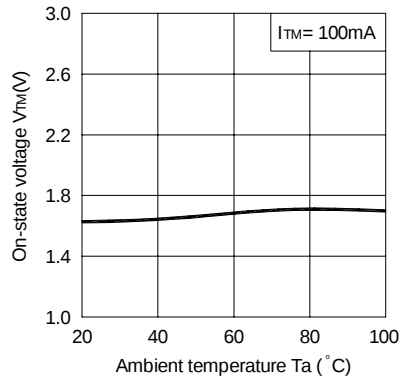
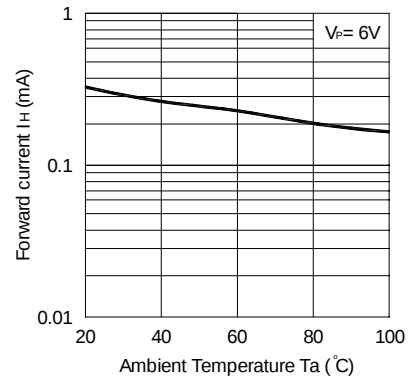


Fig.6 Holding Current vs. Ambient Temperature



CHARACTERISTIC CURVES

Fig.7 Turn-on Time vs. Forward Current

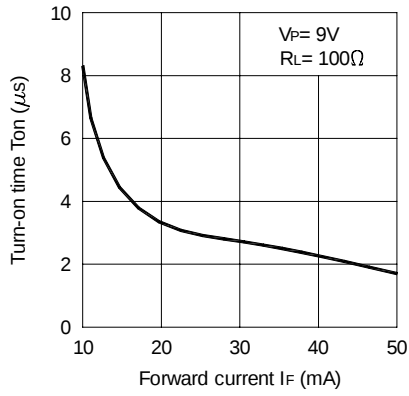


Fig.8 Repetitive Peak Off-state Current vs. Temperature

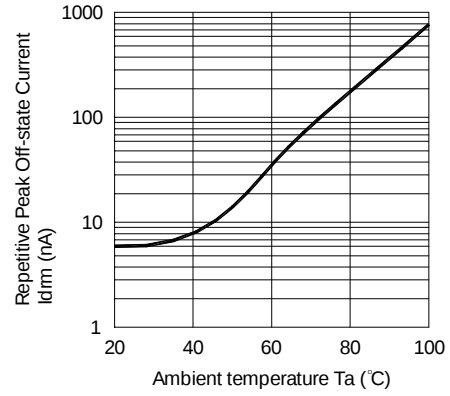
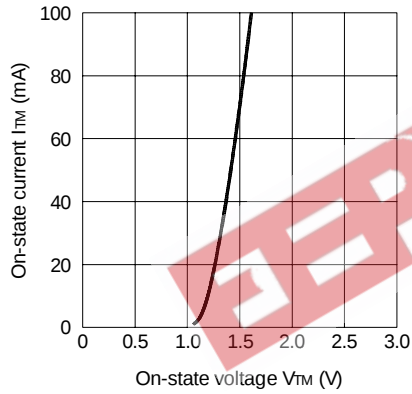


Fig.9 On-state Current vs. On-state Voltage



Static dv/dt Test Circuit

